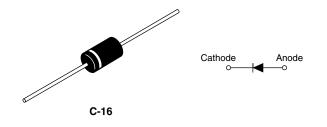
31DQ09G, 31DQ10G

Vishay High Power Products

Schottky Rectifier, 3.3 A



PRODUCT SUMMARY				
I _{F(AV)} 3.3 A				
V _R	90/100 V			

FEATURES

- Low profile, axial leaded outline
- High frequency operation
- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation forenhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long termreliability
- Lead (Pb)-free plating
- Designed and qualified for industrial level

DESCRIPTION

The 31DQ..G axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	3.3	А			
V _{RRM}		90/100	V			
I _{FSM}	t _p = 5 μs sine	370	А			
V _F	3 Apk, T _J = 25 °C	0.85	V			
TJ		- 40 to 150	°C			

VOLTAGE RATINGS							
PARAMETER	SYMBOL	31DQ09G	31DQ10G	UNITS			
Maximum DC reverse voltage	V _R	90	100	V			
Maximum working peak reverse voltage	V _{RWM}	90	100	v			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS		UNITS	
Maximum average forward current See fig. 4	I _{F(AV)}	AV) 50 % duty cycle at $T_C = 53.4$ °C, rectangular waveform		3.3		
Maximum peak one cycle non-repetitive surge current, $T_J = 25 \ ^\circ C$ I _{FSM} See fig. 6		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	370	А	
		10 ms sine or 6 ms rect. pulse	V _{RRM} applied	60		
Non-repetitive avalanche energy	E _{AS}	T_J = 25 °C, I_{AS} = 1 A, 18 µs square pulse		3.0	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.5	А	







Vishay High Power Products Schottky Rectifier, 3.3 A



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
	V _{FM} ⁽¹⁾	3 A	T ₁ = 25 °C	0.85	v	
Maximum forward voltage drop See fig. 1		6 A	1j=25 C	0.97		
		3 A	T.i = 125 °C	0.69		
		6 A	1j = 125 °C	0.80		
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C		0.1	mA	
See fig. 2	IRM ("	T _J = 125 °C	$V_R = Rated V_R$	3		
Typical junction capacitance	CT	V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		110	pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 9.		9.0	nH	
Maximum voltage rate of charge	dV/dt	Rated V _R 10 000 V/µs			V/µs	

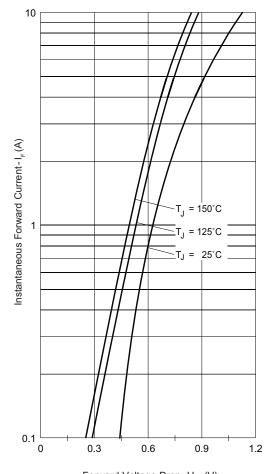
Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

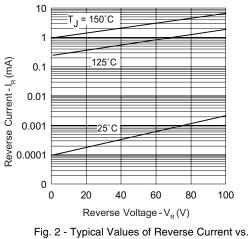
THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 150	°C	
Maximum thermal resistance, junction to ambient	R _{thJA}	R _{thJA} DC operation Without cooling fin		°C/W	
Typical thermal resistance, junction to lead	R _{thJL}	DC operation	34	0/11	
Approvimeto weight			1.2	g	
Approximate weight			0.042	0Z.	
Marking device		Case style C 16	31DQ09G		
		Case style C-16		31DQ10G	



Schottky Rectifier, 3.3 A Vishay High Power Products



 $\label{eq:Forward} \mbox{ Voltage Drop - V}_{_{FM}}(V)$ Fig. 1 - Maximum Forward Voltage Drop Characteristics



Reverse Voltage

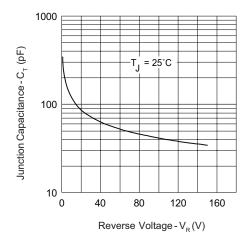
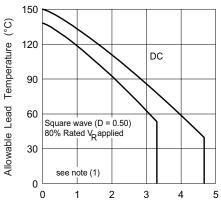
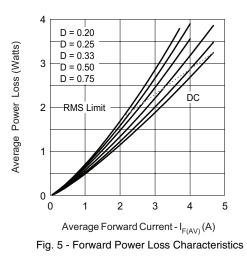


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



Average Forward Current - $I_{F(AV)}(A)$

Fig. 4 - Maximum Allowable Lead Temperature vs. Average Forward Current



Note

⁽⁶⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

31DQ09G, 31DQ10G

Vishay High Power Products Schottky Rectifier, 3.3 A



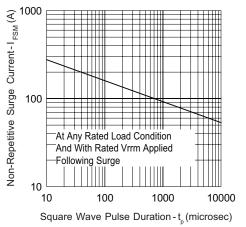


Fig. 6 - Maximum Non-Repetitive Surge Current

ORDERING INFORMATION TABLE

Device code	31	D	Q	10	G	TR	-	
	1	2	3	4	5	6	7	
	1 - 2 - 3 - 4 - 5 - 6 - 7 -	D = 1 Q = 1 G = 1 • No • TR • No	3.3 A (a DO-41 p Schottky Voltage Schottky ne = Bo a = Tape ne = Sta F = Leae	oackage y Q ser e ratings y genera x packa and ree andard p	ies ge (500 el packa productio	09 = 10 = 1 pcs) ge (120	90 V 100 V	ent is x 10)

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95242				
Part marking information	http://www.vishay.com/doc?95304			
Packaging information	http://www.vishay.com/doc?95309			
SPICE model	http://www.vishay.com/doc?95300			



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.